

Radiation-Hard Optical link for the ATLAS Pixel Detector

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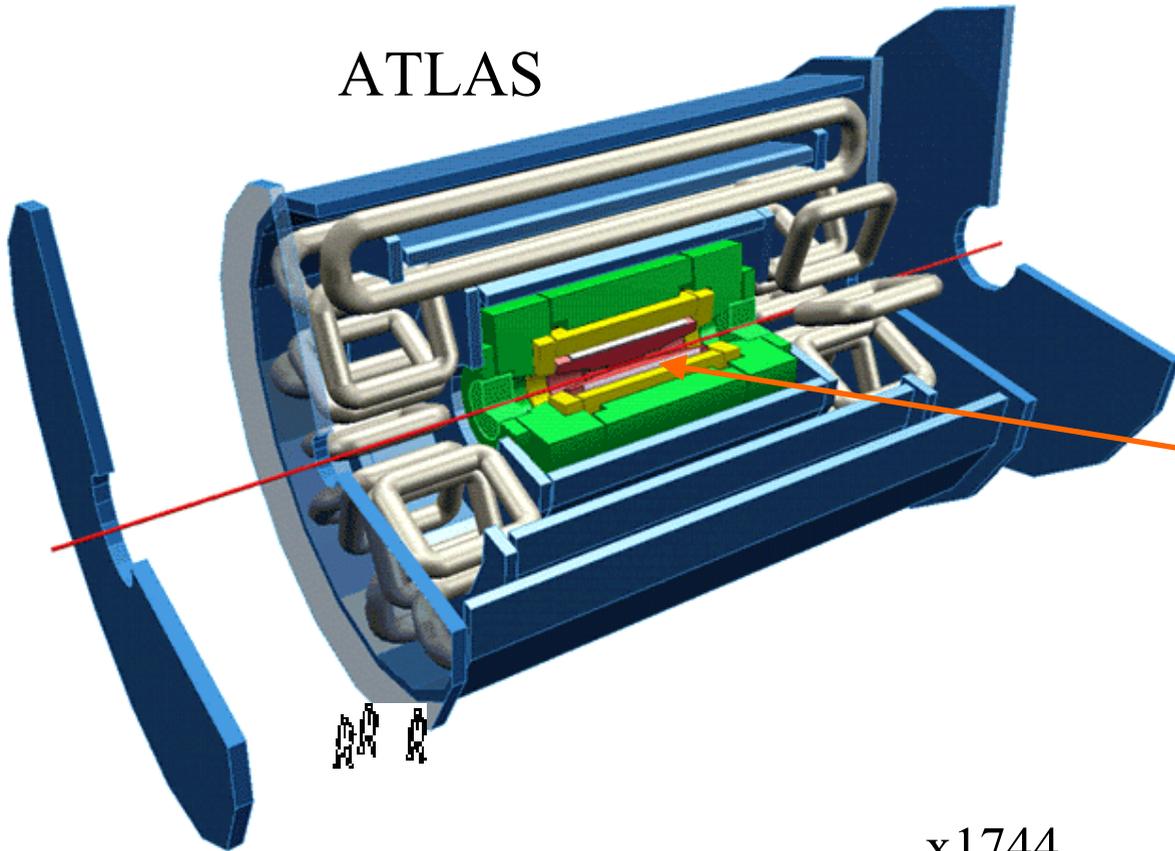
Universitaet Siegen, Germany

Overview

- ATLAS pixel detector
- Pixel Opto-link system
- The VDC and DORIC
- BeO Optoboard
- Proton Irradiation studies
- Production status

Overview: The scale of things

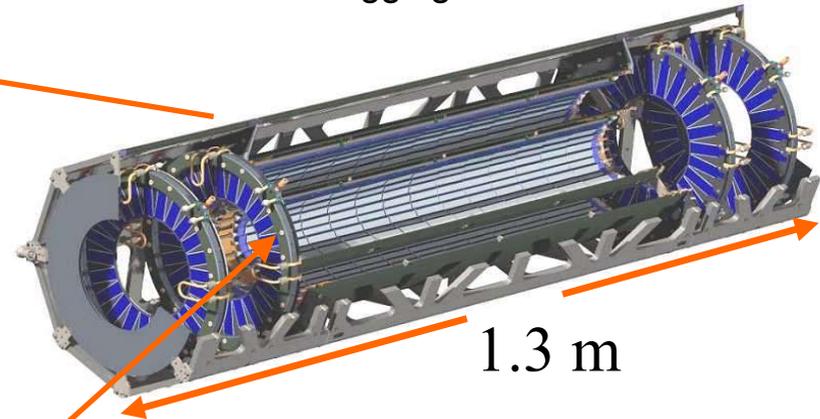
ATLAS



–ATLAS Pixel Detector

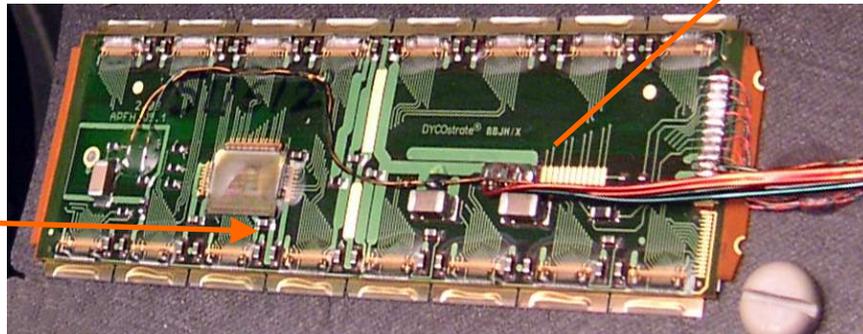
Innermost sub detector, provides

- precise tracking in high multiplicity environment
- 3D-vertexing
- B meson tagging



1.3 m

x1744



x46080

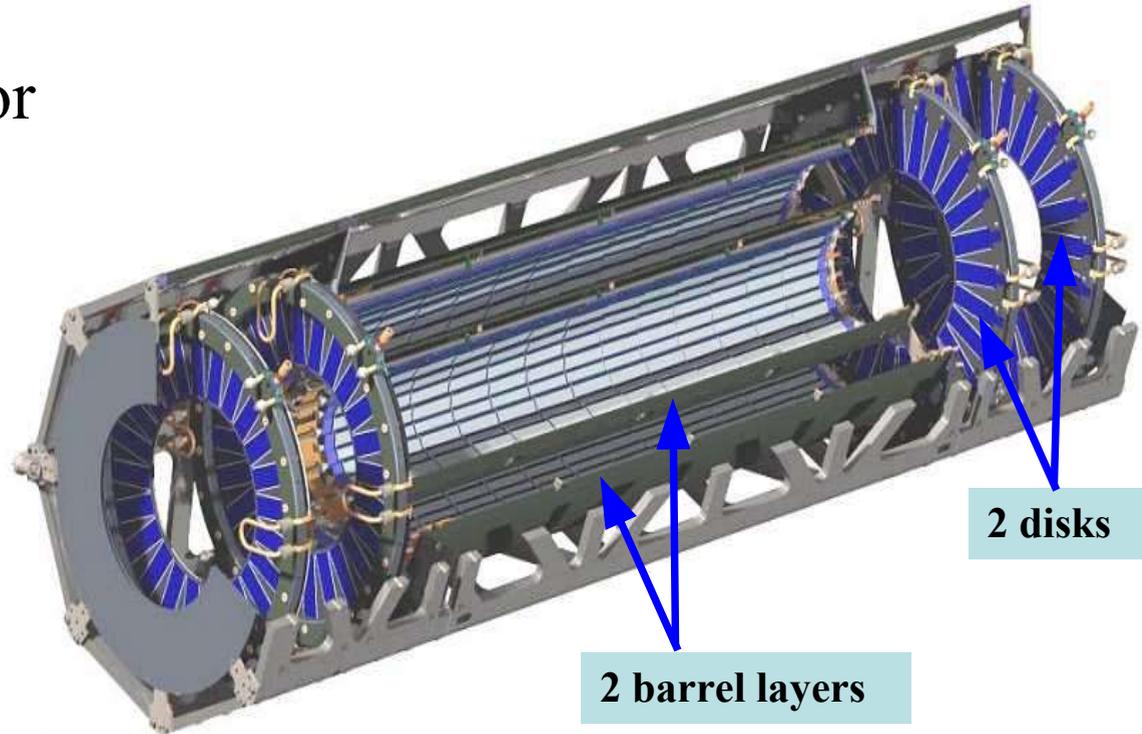


50 x 400 μm

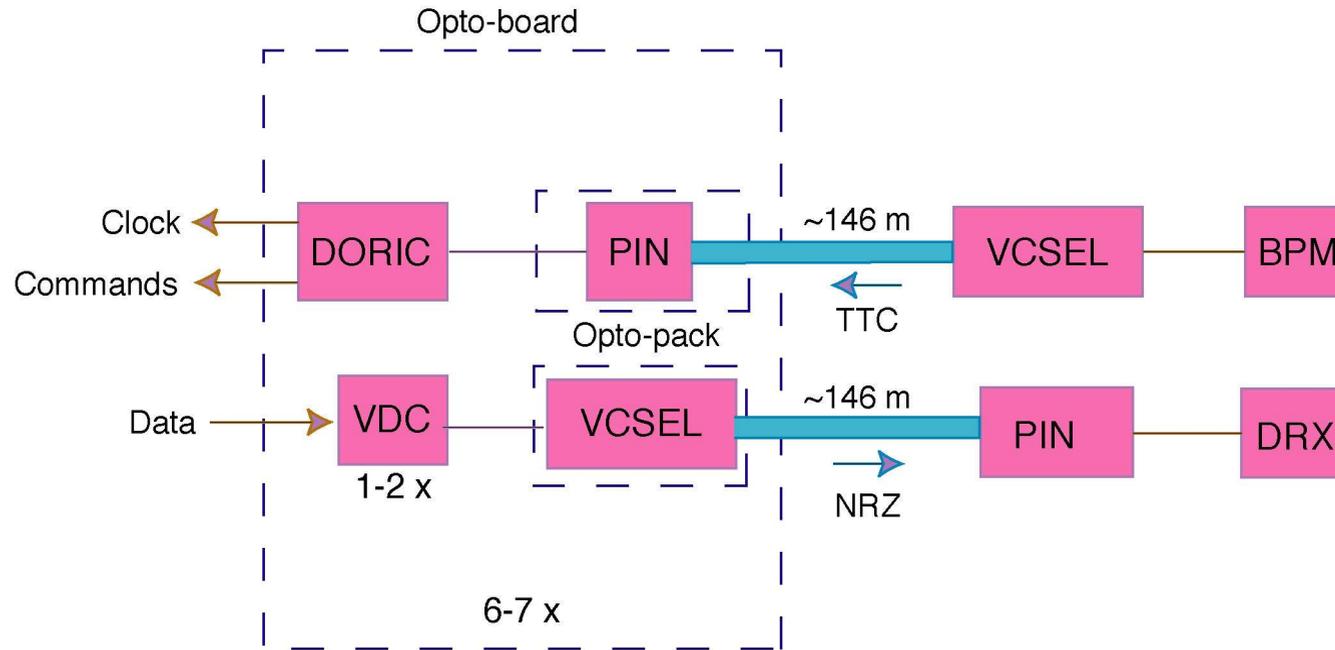
ATLAS Pixel Detector Module. Production is underway. Will focus on optical electronics today.

ATLAS Pixel Detector

- Inner most tracking detector
- Pixel size: $50\mu\text{m} \times 400\mu\text{m}$
- ~100 million channels
- Barrel layers at $r = 5.1$ and 12.3 cm
- Disks at $z = 50$ and 65 cm
- Dosage after 10 years \Rightarrow optical link: 17 Mrad
or 3.7×10^{14} 1-MeV $n_{\text{eq}}/\text{cm}^2$



ATLAS Pixel Opto-link



VCSEL: Vertical Cavity Surface Emitting Laser diode

VDC: VCSEL Driver Circuit

PIN: PiN diode

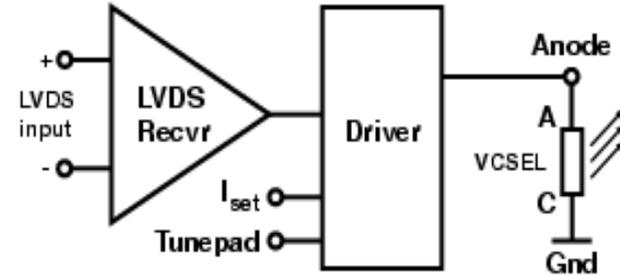
DORIC: Digital Optical Receiver Integrated Circuit

Opto-link system design

- A simple and elegant solution for the pixel detector optolink
- Only 3 flavours of boards: B boards, left D and right D boards
- Modular design **reduces complexity and is easier to build**
- **Problems have been tracked down relatively quickly**
- Wirebonds encapsulated for ease of handling and protection against breakage due to vibrations.
- **Optoboard construction has been fast (~7 months to complete)**

VDC: VCSEL Driver Circuit

- Convert LVDS input signal into single-ended signal appropriate to drive VCSEL diode
- Output (bright) current: 0 to 20 mA controlled by external current I_{set}
- Standing (dim) current: ~ 1 mA improve switching speed
- Rise & fall times: 1 ns nominal for 40 MHz signals
- “On” voltage of VCSEL: up to 2.3 V at 20 mA for 2.5 V supply
- Constant current consumption!
- Use Truelight high-power oxide common cathode VCSEL array



DORIC: Digital Optical Receiver IC

Decode **Bi-Phase Mark** encoded (**BPM**) clock and command signals from PIN diode

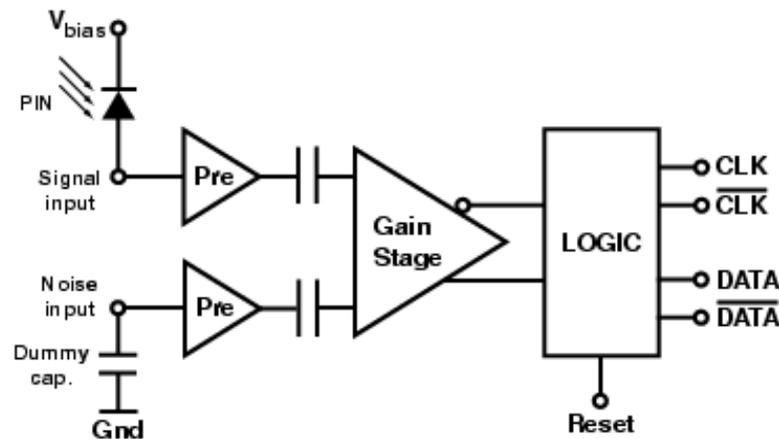
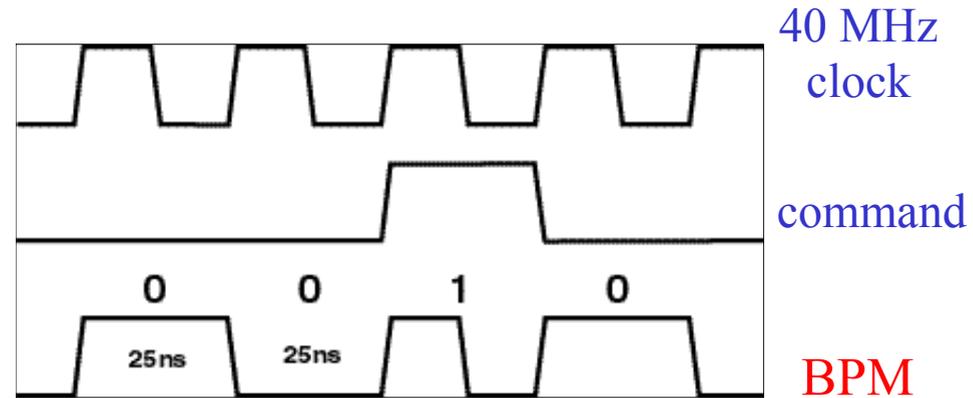
Input signal: **40-1000 μ A**

Extract: **40 MHz clock**

Duty cycle: **$(50 \pm 4)\%$**

Total timing error: **< 1 ns**

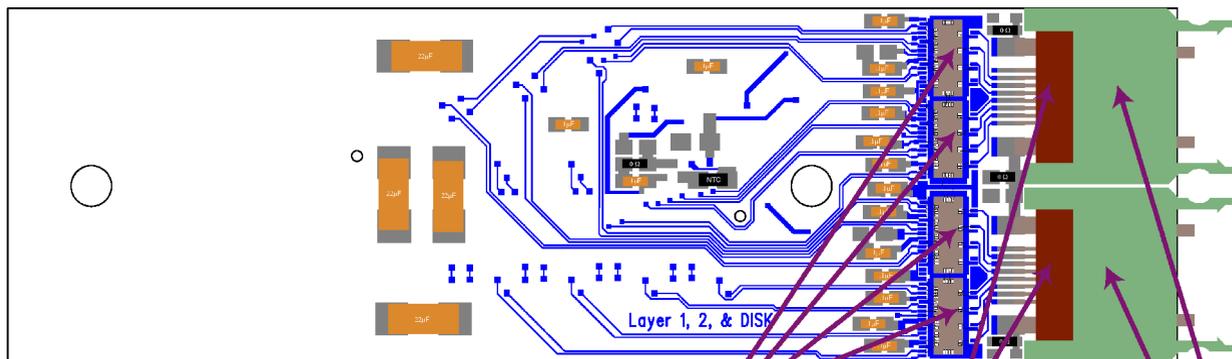
Bit Error Rate (BER):
 $< 10^{-11}$ at end of life
Use Truelight common cathode PIN array



Optoboard

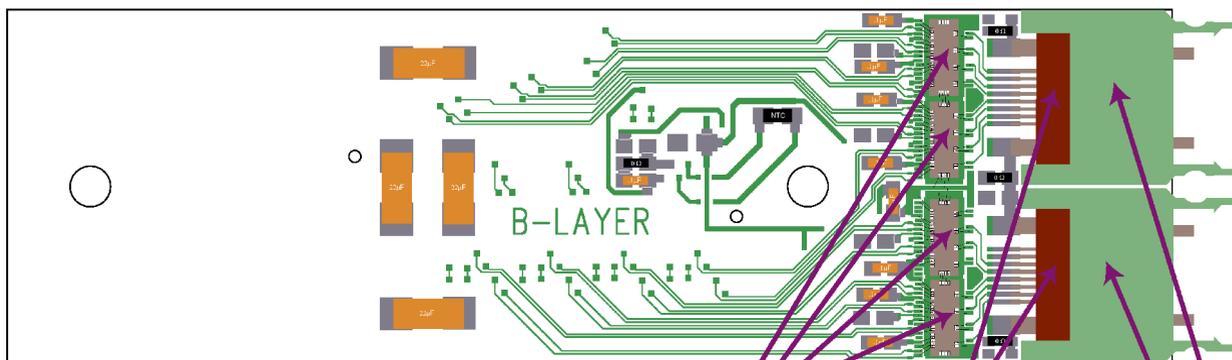
- Converts: **optical signal** \Leftrightarrow **electrical signal**
- Contains 7 optical links, each link serving one pixel module
 - Layer D: for outer barrel and disks, only one data link per module (228 boards).
 - Layer B: for inner barrel, two data links per module to accommodate for high hit occupancy (44 boards).
- Fabricated with BeO for heat management

Optoboard design and Layout



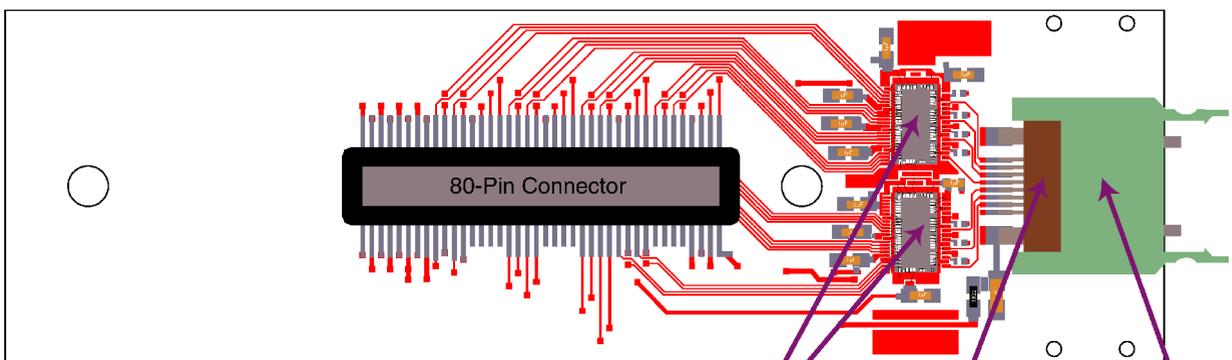
TOP
(outer barrel layer and disk)

4-channel VDC VCSEL opto-pack Housing



TOP
(inner barrel layer)

4-channel VDC VCSEL opto-pack Housing

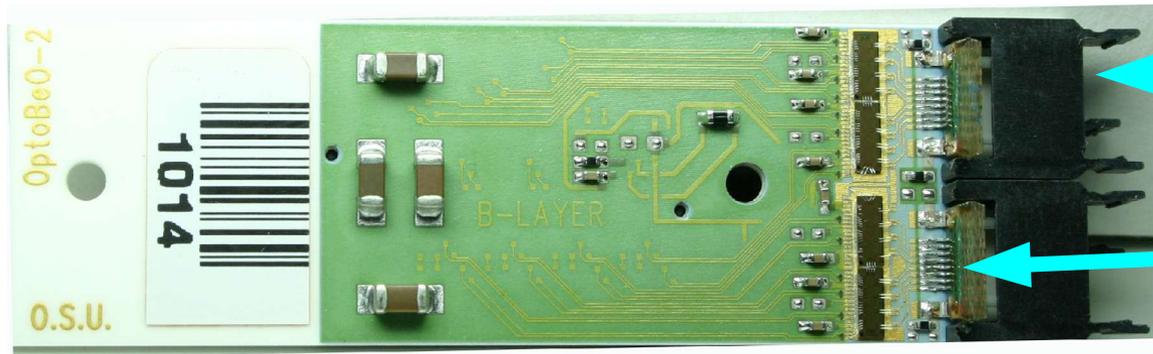


BOTTOM

1 cm

4-channel DORIC PIN opto-pack Housing

BeO Optoboard

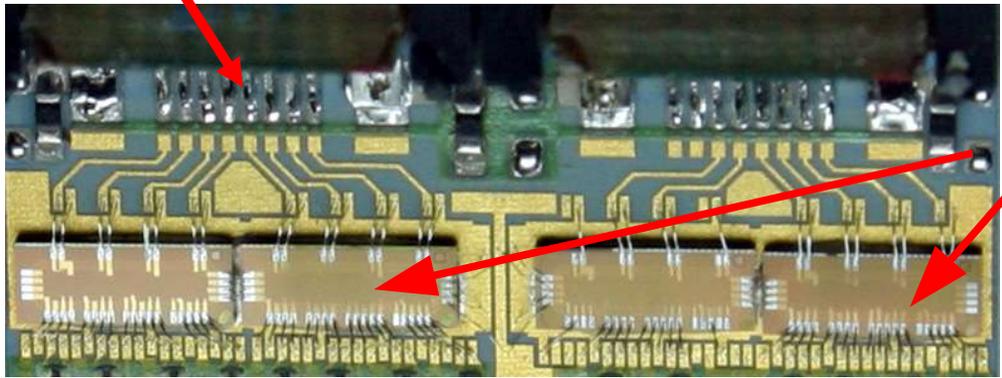


Housing

Opto-pack

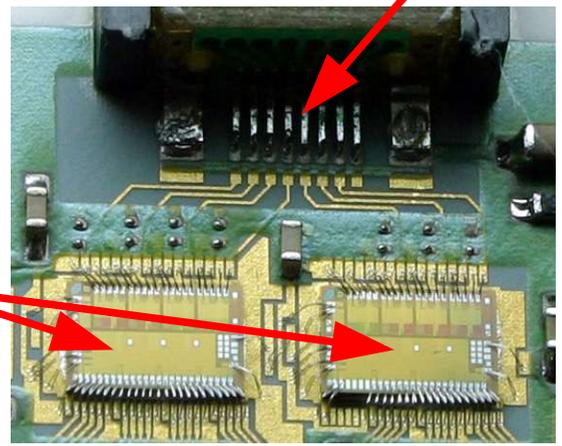
VCSEL-pack

PIN-pack

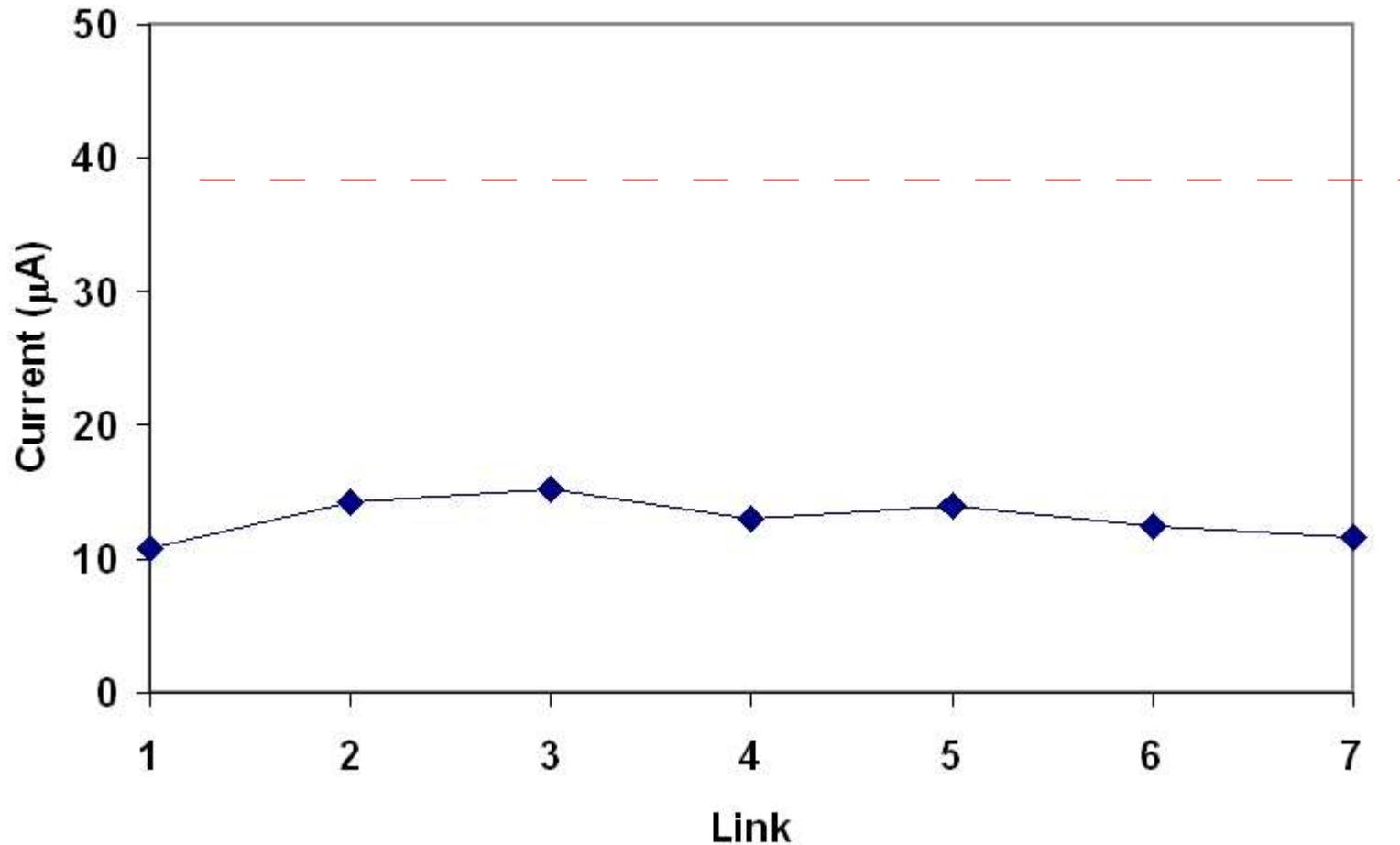


VDC

DORIC

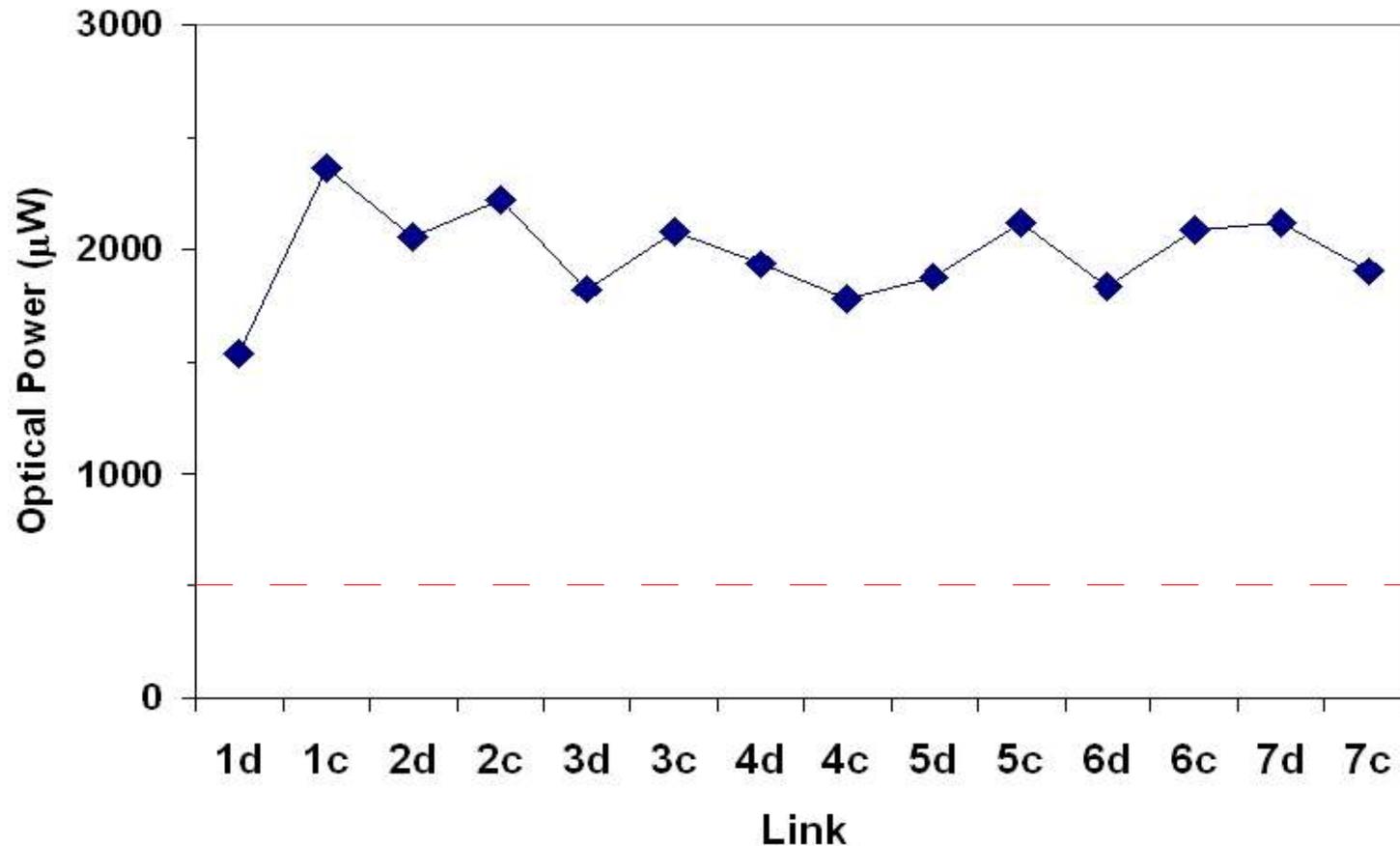


Minimum PIN Current for No Bit Error



- Minimum PIN current for no bit error for all links active is significantly below the spec. of $40\mu\text{A}$

Optical Power

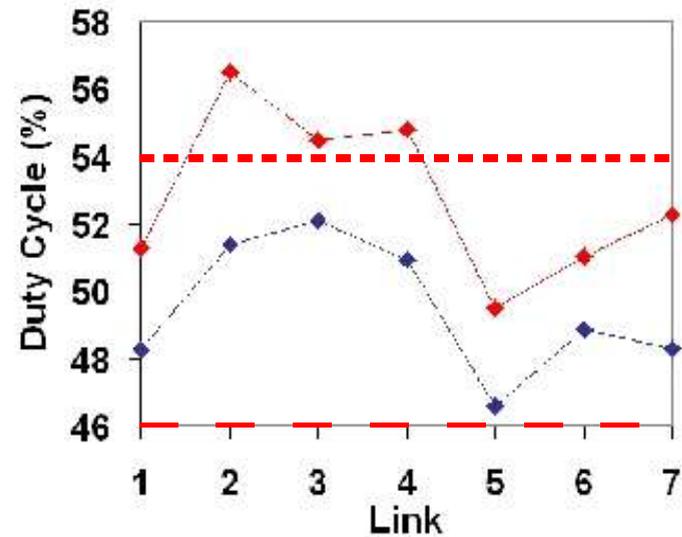
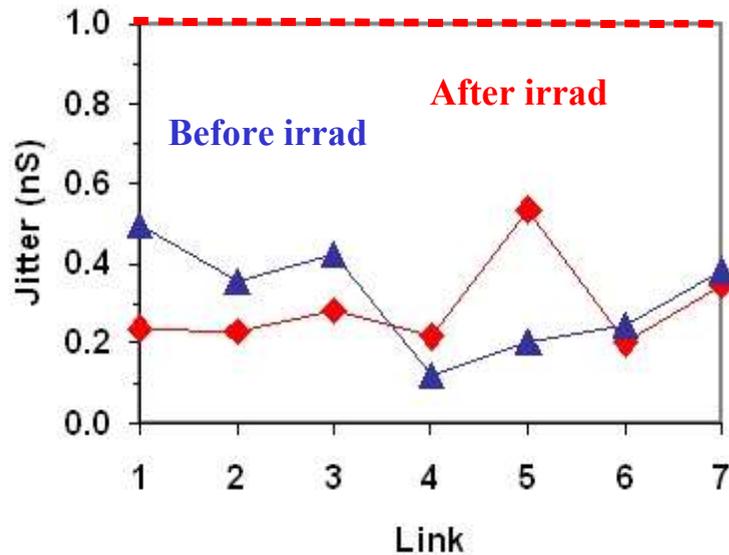


- Excellent optical power
 - Significantly above the minimum requirement of $500\mu\text{W}$

Radiation Hardness Measurements of Opto-boards

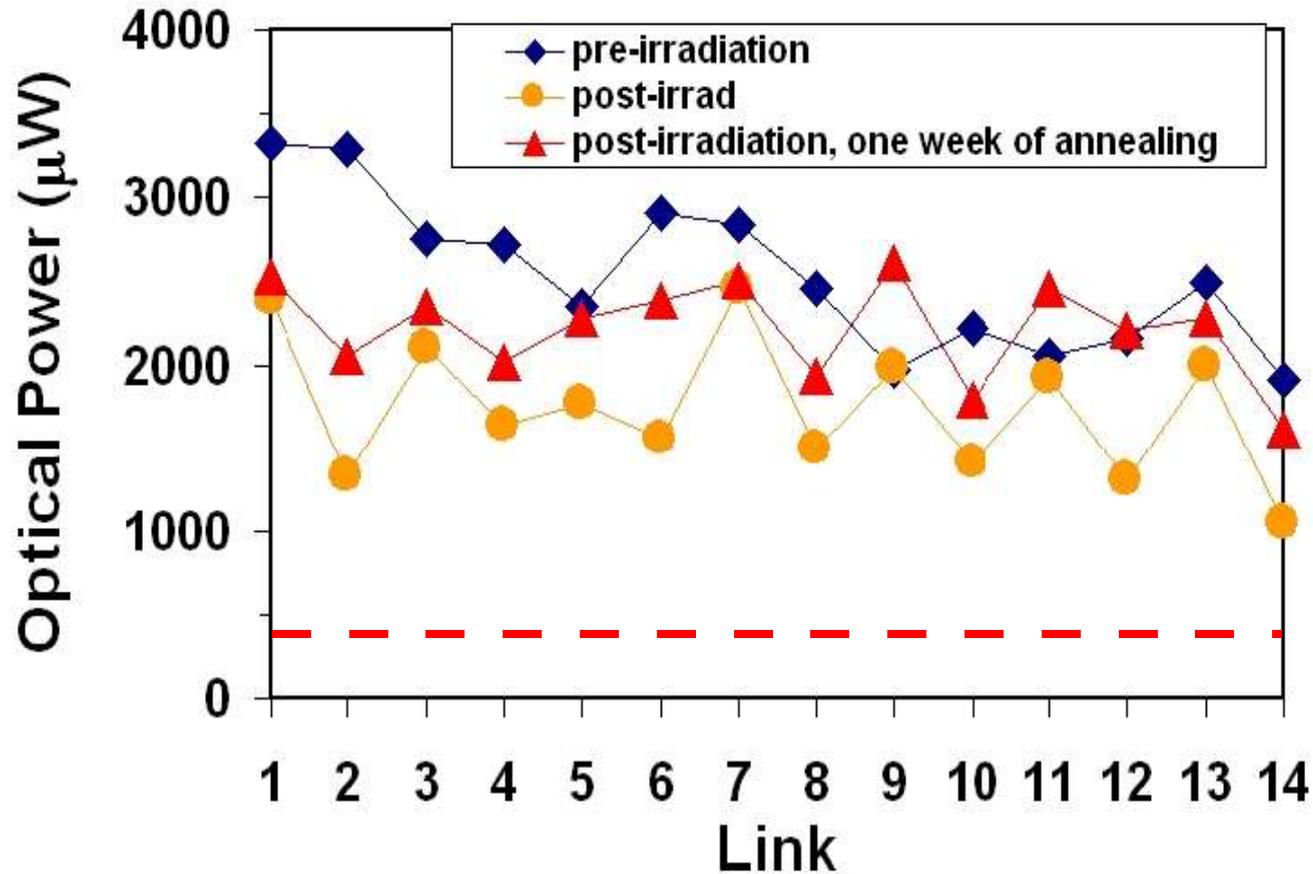
- Use CERN's T7 beam (24 GeV Proton) for radiation hardness
 - T7 shuttle setup
 - Boards can be moved in and out of beam remotely for annealing
 - Real time testing of opto-board system using loop-back setup
 - Compare transmitted and decoded data
 - measure minimum PIN current for no bit errors
 - Measure optical power
- Last irradiation in June 2004
 - Four BeO opto-boards were irradiated with up to 32 Mrad
 - Received at OSU late 2004

Duty Cycle, Jitter and Rise/Fall times



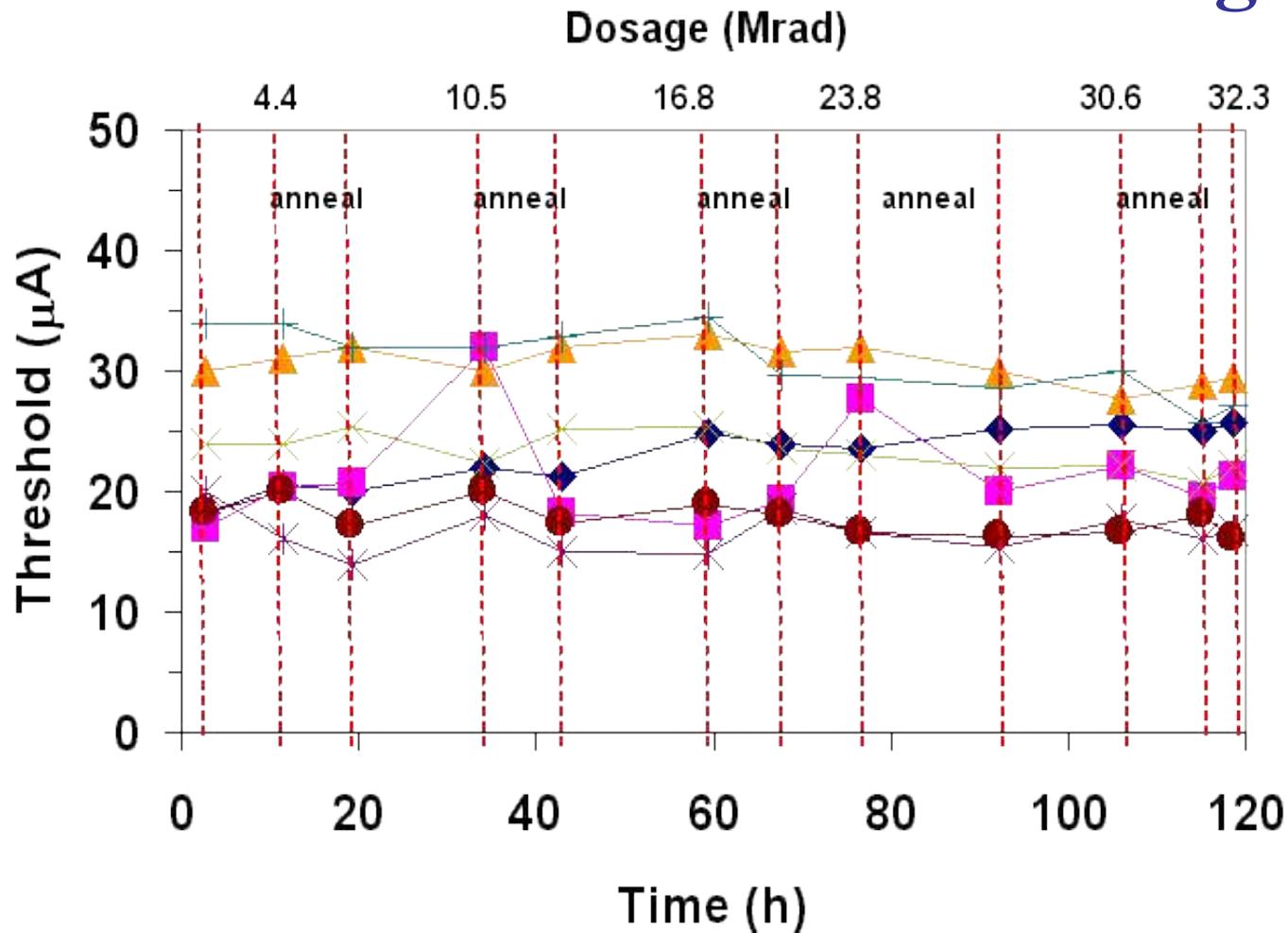
- Jitter, and rise and fall times (not shown) are within the spec.
- Duty cycle slightly higher than 54% in three of the links.

Optical Power



- Some degradation in power after irradiation
 - Power is significantly above the minimum required $\sim 350 \mu\text{W}$
- Annealing (for VCSELs) recovers most of the lost power

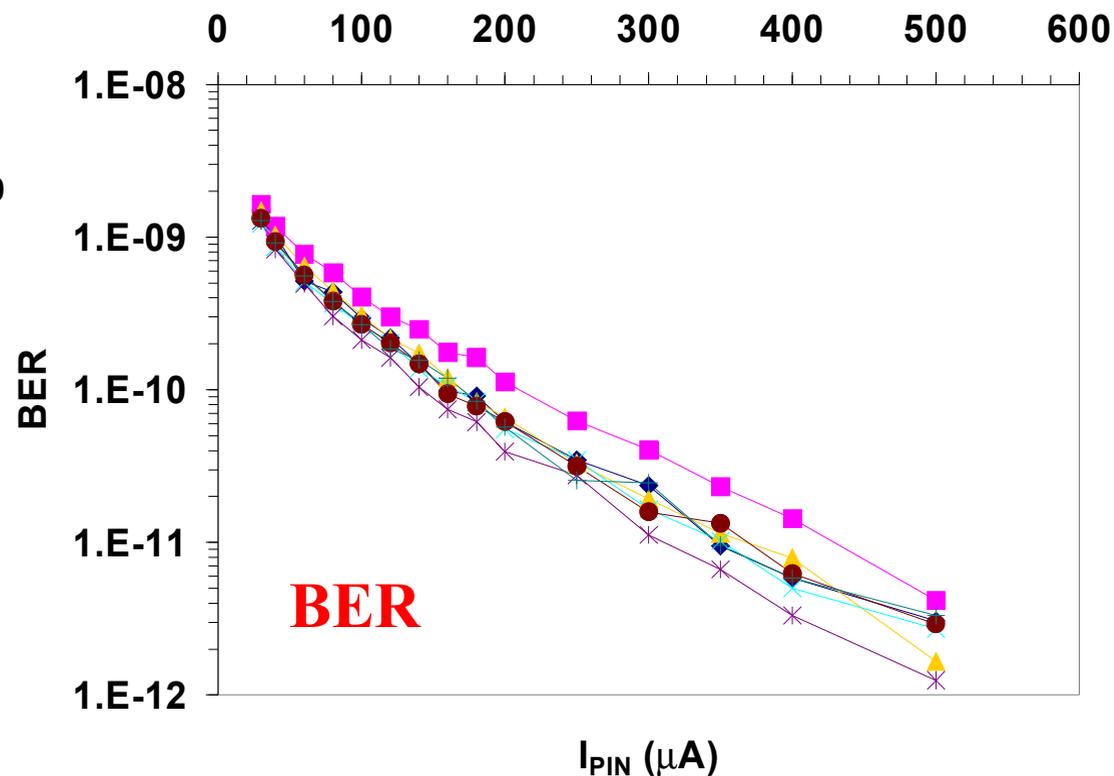
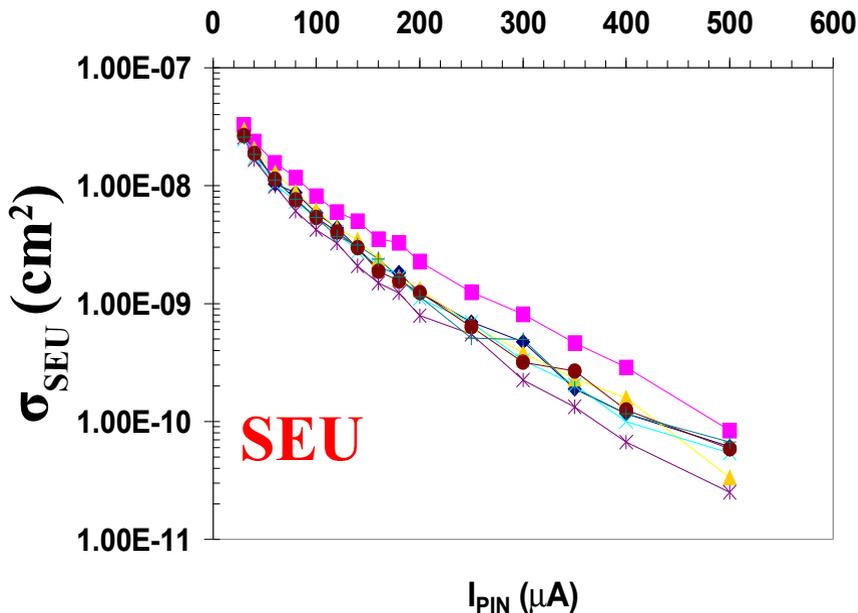
PIN Current Threshold vs Dosage



- PIN current thresholds for no bit errors remain constant

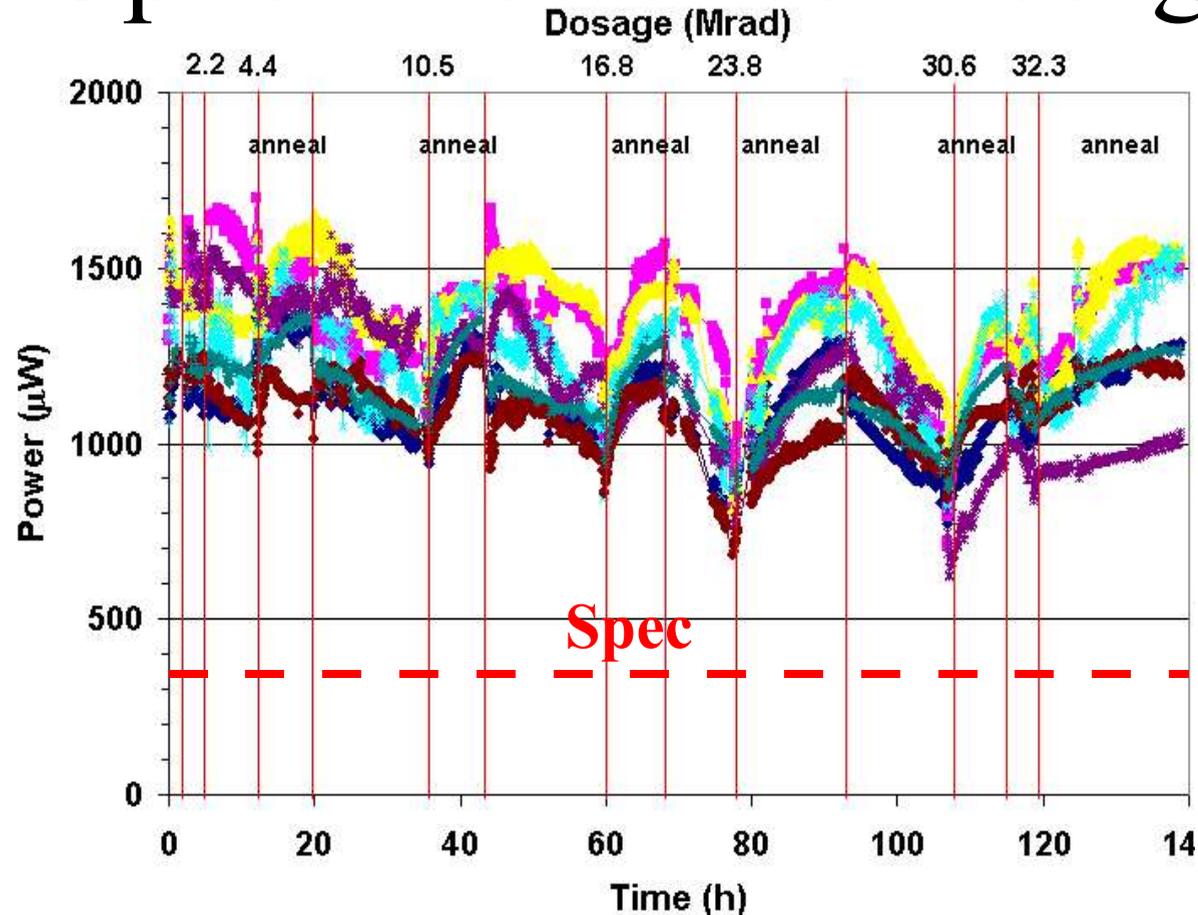
Proton Induced Bit Errors in PIN

- Convert bit errors to bit error rates at opto-link



- Bit error rate decreases with PIN current as expected
- Bit error rate: $\sim 3 \times 10^{-10}$ at 100 μA (1.4 errors/minutes)
 - DORIC spec: 10^{-11}
 - Opto-link error rate is limited by SEU

Optical Power vs. Dosage



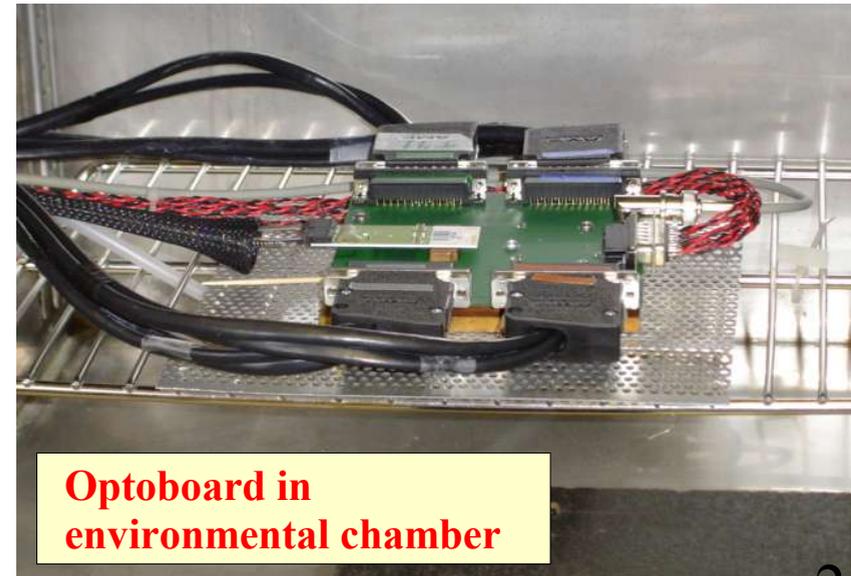
- Irradiation procedure: ~ 5 Mrad/day (10 hours) with annealing rest of the day
- Optical power decreases with dosage as expected
- Limited annealing recovers some lost power
- Still good power after 30 Mrad

Production Status

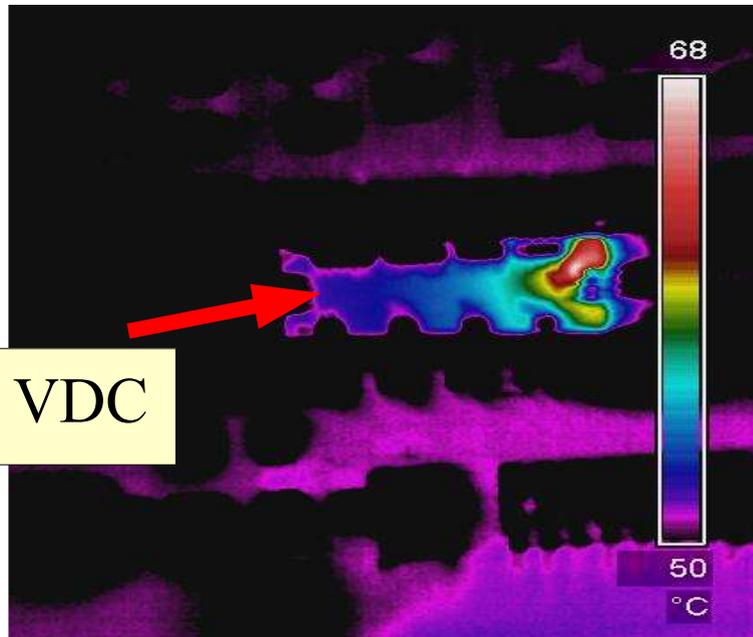
- We began optoboard production for ATLAS in February 2005.
- Very aggressive schedule to complete by September/October.
- Required producing ~10 optoboards/week at OSU (challenging).
- Within one week of starting production we turned everything off and moved to a new lab in a new physics building !!! Initial upheaval but we now have a much larger lab space to work in.
- Our colleagues at Siegen will also be producing optoboards.

Production Challenges

- Making many boards in a week is driven by rigorous QA procedure
 - 72 hours burn-in at 50°C
 - 10 Thermal cycles between -25°C and 50°C (takes 18 hours)
 - Testing optical and electrical QA (takes ~1 day per board)
 - We use 2 environmental chambers and 2 additional ovens.
 - Implimented an 'early shift' to extend the work day



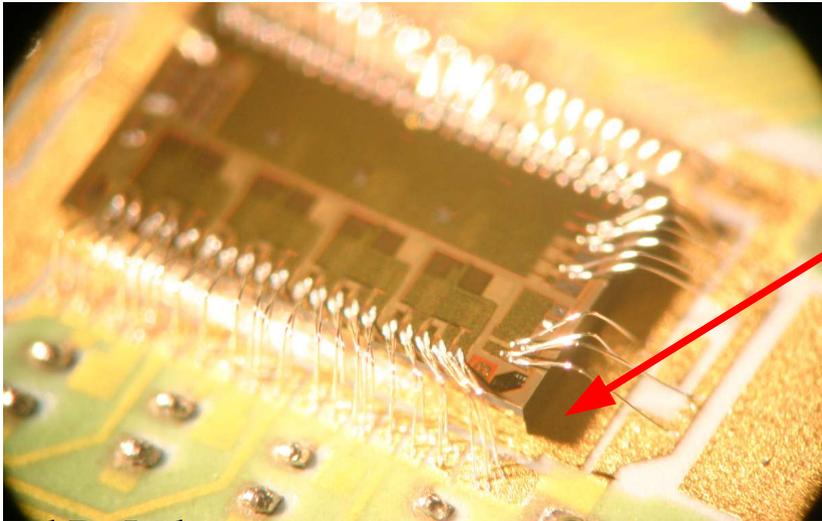
Initial Optoboard production problem



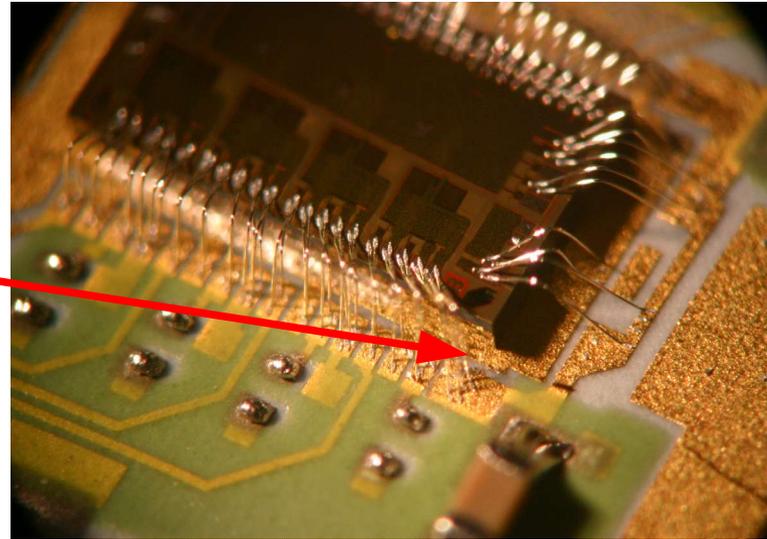
- Thermal images revealed shorts to ground through the chips where large current was being drawn.
- Since this issue, we have implemented testing of ALL chips
- Haven't seen the problem since. Also test duty cycle of DORICs.
- Reworked the boards with failed chips, remove wirebonds, put on new chip.

Reworked boards

- We implemented a procedure to salvage the boards that were populated with failed chips.
- Strip wire bonds, stick a new chip on top of the failed one, bond to that chip, then QA (burn-in, thermal cycle etc).
- So far we have recovered 12 boards in this way and have seen no obvious problems with the reworks. **ALL reworks are considered second class.**

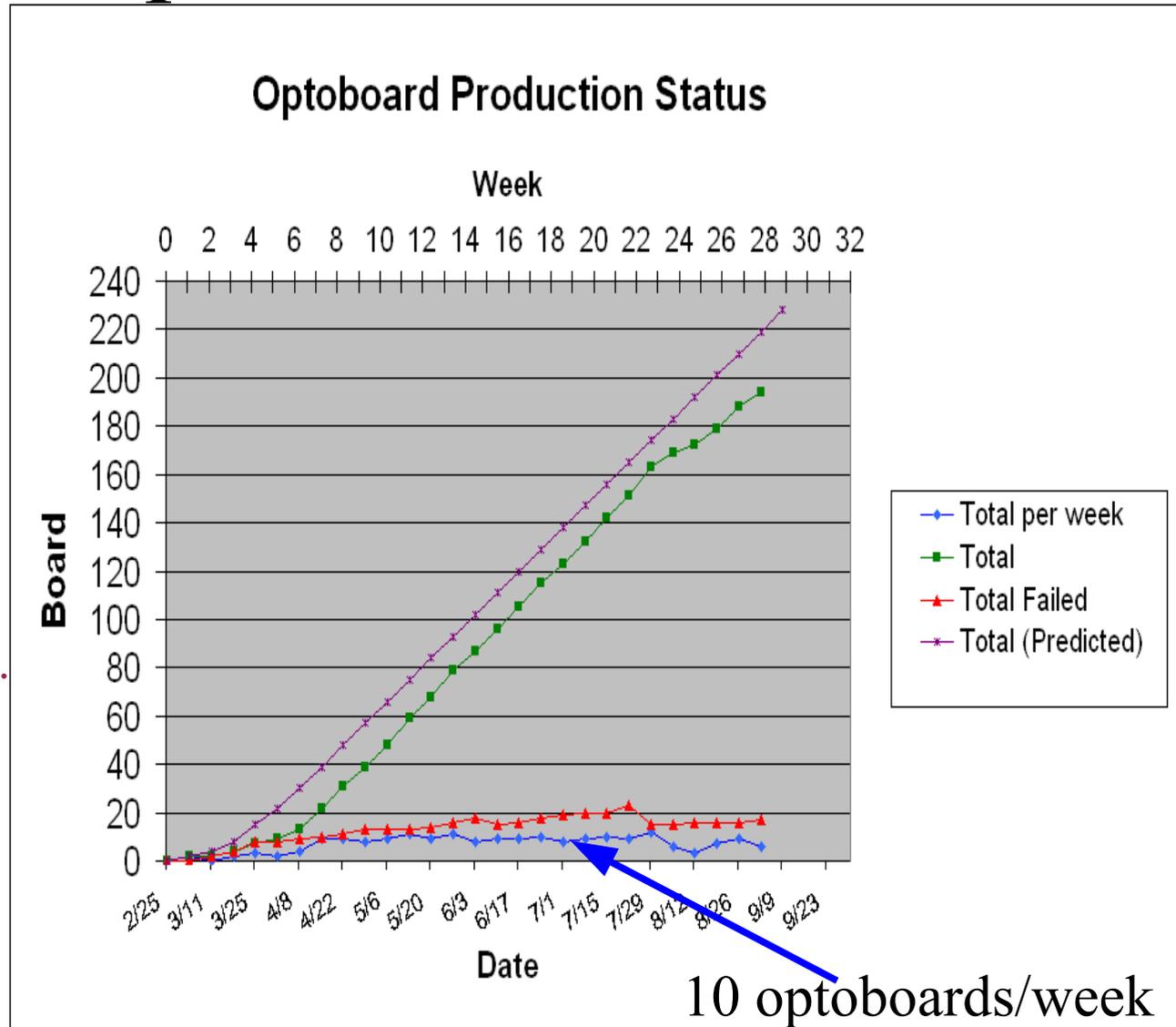


Two chips
thickness
seems to
work fine!!



Optoboard production status

- Our rate started out slower than expected with more failures than anticipated.
- After ~6 weeks we reached target production rate.
- Maintained good yield for many weeks now.
- If we can continue at our current rate, and efficiency, reach production goal in Sept.
- Reworked failed boards to salvage them....and add them to the green curve.



Summary

- Optical link plays a crucial role in the ATLAS pixel detector
- Using BeO optoboard substrate for heat management
- VDC and DORIC chips have been tested extensively for radiation hardness.
- We are in production mode now and expect to complete all optoboards by the end of September.